| PCI | N Number: | 20220913 | 3000.2 | PCN Da | September 13, 2022 | | | |
|---|--|---|---|--|---------------------------|--|--|--|
| Titl | e: Qualifica | ation of Cu | as an alternate | oond wire & other BC |)M elements | for Select Devices | | |
| Cus | stomer Conta | ct: PCN | Manager Dept | Quality Ser | vices | | | |
| Pro | posed 1 st Shi | p Date: | Mar 12, 2023 | - | Requests ted until: | Oct 13, 2022 | | |
| | | ts receive | ed after Oct 13, | 2022 will not be su | pported. | | | |
| Cha | ange Type: | | | | | | | |
| | Assembly Site | | Desig | | | · Bump Site | | |
| | Assembly Pro | | | Sheet | | Bump Material | | |
| | Assembly Mat | | | number change | | Bump Process | | |
| | Mechanical S | • | | | | Fab Site | | |
| Ш | Packing/Shipp | oing/Labeli | ng □ lest | Process | | Fab Materials | | |
| | | | D.C. | N Dataila | □ Wafer | Fab Process | | |
| Dat | - avintian of Cl | h-n | PC | N Details | | | | |
| Des | scription of Cl | nange: | | | | | | |
| | product affec | | | vire & new die coat o | | dditional | | |
| | Current P | Bond wire | | | | | | |
| | Dian | neter | Au, 1.0 | , 1.2, or 1.3 mils | Cu, 0 | Cu, 0.8 or 1.3 mils | | |
| | וום ו חבונו | : Material | | | | PI | | |
| | Die Coat | ···acciiai | | ВСР | | PI | | |
| | ason for Chan | ge: | | ВСР | | PI | | |
| Cor 1) 2) 3) | ason for Chan ntinuity of supp To align with welectrical prop Maximize flexib Cu is easier to | ge: bly. world tech erties bility withir obtain an | our Assembly/Tod d stock | d use wiring with enhest production sites. Quality or Reliabi | | nanical and | | |
| Cor 1) 2) 3) | ason for Chan atinuity of supp To align with velectrical prop Maximize flexib Cu is easier to | ge: bly. world tech erties bility withir obtain an | our Assembly/Tod d stock | d use wiring with enhest production sites. | | nanical and | | |
| 2) 3) Ani Nor | ason for Chan atinuity of supp To align with velectrical prop Maximize flexib Cu is easier to | ge: bly. world tech perties bility within botain an | our Assembly/Tod d stock m, Fit, Function | d use wiring with enhest production sites. | | nanical and | | |
| Cor 1) 2) 3) Ant Nor Imp | ason for Chan atinuity of supp To align with velectrical prop Maximize flexib Cu is easier to cicipated import pact on Environ ecked boxes income | ge: oly. world tech perties oility within obtain an act on For onmental | n our Assembly/Tod stock Tm, Fit, Function Ratings status of environ | d use wiring with enhest production sites. | lity (positiv | nanical and ve / negative): | | |
| Cor 1) 2) 3) Ant Nor Imp | ason for Chan atinuity of supp To align with velectrical prop Maximize flexib Cu is easier to ticipated impa ne pact on Environ cked boxes income. If below he | ge: oly. world tech perties oility within obtain an act on For onmental | n our Assembly/Tod stock Tm, Fit, Function Ratings status of environ | d use wiring with enhancest production sites. Description (Application) D | lity (positive) | nanical and ve / negative): | | |
| Cor 1) 2) 3) Ant Nor Imp | ason for Chan atinuity of supp To align with a electrical prop Maximize flexib Cu is easier to cicipated impa ne ecked boxes inc nge. If below l ngs. | ge: oly. world tech perties oility within obtain an act on For onmental dicate the boxes are | Ratings status of enviror checked, there a | d use wiring with enhancest production sites. Description of Reliability or Reli | ring implement associated | nanical and ve / negative): entation of this environmental | | |
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| Cor 1) 2) 3) Ant Nor Imp Che cha ratio | ason for Chan atinuity of supp To align with velectrical prop Maximize flexib Cu is easier to cicipated impa and acked boxes income. If below boxes If below | ge: oly. world tech perties oility within obtain an act on For onmental dicate the boxes are | Ratings status of enviror checked, there a REACH No Change | d use wiring with enhancest production sites. The entire of Reliability or Relia | ring implement associated | nanical and ve / negative): entation of this environmental IEC 62474 | | |
| Cor 1) 2) 3) Ant Nor Imp Che cha ratio | ason for Chan atinuity of supp To align with a electrical prop Maximize flexib Cu is easier to ticipated impa acked boxes income. If below in the lectrical prop RoHS No Change | ge: oly. world tech perties oility within obtain an act on For onmental dicate the boxes are | Ratings status of enviror checked, there a REACH No Change | d use wiring with enhancest production sites. The American Production sites are no changes to the Manage are no change are no c | ring implement associated | nanical and ve / negative): entation of this environmental IEC 62474 | | |
| Cor 1) 2) 3) Ant Nor Imp Che cha ratii | ason for Chan atinuity of supp To align with a electrical prop Maximize flexib Cu is easier to ticipated impa acked boxes income. If below in the lectrical prop RoHS No Change | ge: oly. world tech perties oility within obtain an act on For onmental dicate the boxes are | Ratings status of enviror checked, there a REACH No Change | d use wiring with enhancest production sites. The American Production sites are no changes to the Manage are no change are no c | ring implement associated | nanical and ve / negative): entation of this environmental IEC 62474 | | |
| Checharatii | ason for Chan atinuity of supp To align with to electrical prop Maximize flexib Cu is easier to ticipated impa ne expect on Enviro ecked boxes inco nge. If below Ings. RoHS No Change anges to prod ne | ge: bly. world tech perties bility within botain an act on For commental dicate the boxes are | Ratings status of enviror checked, there a REACH No Change | d use wiring with enhancest production sites. Description of the production sites. Description of the production sites. Description of the production of the production sites. Description of the production o | ring implemer associated | nanical and ve / negative): entation of this environmental IEC 62474 No Change | | |
| Cor 1) 2) 3) Ant Nor Imp Che cha ratii | ason for Chan attinuity of supp To align with velectrical prop Maximize flexib Cu is easier to ticipated impa and the control of the control and the control | ge: ply. world tech perties polity within potain an act on For commental dicate the boxes are poxes are | Ratings status of enviror checked, there a REACH No Change | d use wiring with enhancest production sites. The American Production sites are no changes to the Manage are no change are no c | ring implemer associated | nanical and ve / negative): entation of this environmental IEC 62474 | | |

| DP83848QSQX/NOPB | LDC1312QDNTTQ1 | LM25117QPSQE/NOPB | LM5117QPSQ/NOPB | |
|------------------|----------------|--------------------|------------------|--|
| FDC2112QDNTRQ1 | LDC1314QRGHRQ1 | LM25117QPSQX/NOPB | LM5117QPSQE/NOPB | |
| FDC2112QDNTTQ1 | LDC1314QRGHTQ1 | LM25119QPSQ/NOPB | LM5117QPSQX/NOPB | |
| FDC2114QRGHRQ1 | LDC1612QDNTRQ1 | LM25119QPSQX/NOPB | LM5119QPSQ/NOPB | |
| FDC2114QRGHTQ1 | LDC1612QDNTTQ1 | LM26420Q1XSQ/NOPB | LM5119QPSQX/NOPB | |
| FDC2212QDNTRQ1 | LDC1614QRGHRQ1 | LM26420Q1XSQX/NOPB | | |



TI Information **Selective Disclosure**

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Qualification of 0.8mil / 1.3mil PCC wire as alternate bonding material for QFN CMOS9T, ABCD5 and PVIP50 for **Automotive Devices** Approved 12-Jul-2022

Product Attributes

| Attributes | Qual Device: DP83848QSQNOPB | Qual Device: LM26420Q1XQMGR | Qual Device: <u>LM5119QPSQX/NO</u> |
|------------------------|--------------------------------|--------------------------------|---------------------------------------|
| Automotive Grade Level | Grade 2 | Grade 1 | Grade 1 |
| Operating Temp Range | -40 to +105 C | -40 to +125 C | -40 to +125 C |
| Product Function | Interface | Interface | Interface |
| Wafer Fab Supplier | MAINEFAB | MAINEFAB | MAINEFAB |
| Die Revision | A | В | A |
| Assembly Site | TIEMA | TIEMA | TIEMA |
| Package Type | WQFN; 6 x 6 MM | QFN; 5 X 5 MM | QFN: 5 X 5 MM |
| Package Designator | RTA | RUM | RTV |
| Ball/Lead Count | 40 | 16 | 32 |

⁻ QBS: Qual By Similarity

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

| Туре | # | Test Spec | Min Lot Qty | SS/Lot | Test Name / Condition | Duration | Qual Device: DP83848QSQNOPB | Qual Device: LM26420Q1XQMGR | Qual Device: LM5119QPSQX/NO | |
|---|----|-------------------------------------|----------------|------------|---|-------------------|--------------------------------|--------------------------------|--------------------------------|--|
| Test Group A – Accelerated Environment Stress Tests | | | | | | | | | | |
| PC | A1 | JEDEC J-STD-020 JESD22-A113 | 3 | 77 | Preconditioning | Level 3-260C | No Fails | No Fails | No Fails | |
| HAST | A2 | JEDEC JESD22-A110 | 3 | 77 | Biased HAST, 110C/85%RH | 264 Hours | - | 3/231/0 | 3/231/0 | |
| UHAST | АЗ | JEDEC JESD22-A118 | 3 | 77 | Unbiased HAST, 110C/85%RH | 264 Hours | 3/231/0 | - | - | |
| TC | A4 | JEDEC JESD22-A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 500 Cycles | 3/231/0 | 3/231/0 | 3/231/0 | |
| TC- WBP | A4 | MIL-STD883 Method 2011 | 1 | 60 | Bond Pull over Ball Post T/C 500 Cycles | Wires | 3/90/0 | 3/90/0 | 3/90/0 | |
| PTC | A5 | JEDEC JESD22-A105 | 1 | 45 | Power Temperature Cycle | 1000 Cycles | N/A | N/A | N/A | |
| HTSL | A6 | JEDEC JESD22-A103 | 1 | 45 | High Temp Storage Bake 150C | 1000 Hours | - | - | 3/135/0 | |
| | | Test Group | B – Accelei | rated Life | time Simulation Tests | | | | | |
| EDR | В3 | AEC Q100-005 | 3 | 77 | NVM Endurance, Data Retention, and Operational Life | - | N/A | N/A | N/A | |
| | | Test Grou | p C – Pack | age Assei | mbly Integrity Tests | | | | | |
| WBS | C1 | AEC Q100-001 | 1 | 30 | Wire Bond Shear (Cpk>1.67) | - | 3/90/0 | 3/90/0 | 3/90/0 | |
| WBP | C2 | MIL-STD883 Method 2011 | 1 | 30 | Wire Bond Pull (Cpk>1.67) | - | 3/90/0 | 3/90/0 | 3/90/0 | |
| SD | С3 | JEDEC JESD22-B102 | 1 | 15 | Surface Mount Solderability >95% Lead Coverage | - | - | - | - | |
| PD | C4 | JEDEC JESD22-B100 and B108 | 3 | 10 | Physical Dimensions (Cpk>1.67) | - | - | - | - | |
| SBS | C5 | AEC Q100-010 | 3 | 50 | Solder Ball Shear (Cpk>1.67) | Post HTSL/Bump | - | - | - | |
| SBS | C5 | AEC Q100-010 | 3 | 50 | Solder Ball Shear (Cpk>1.67) | Solder Balls | - | - | - | |
| LI | C6 | JEDEC JESD22-B105 | 1 | 50 | Lead Integrity | - | - | - | - | |

⁻ Qual Device LM5119QPSQX/NO is qualified at LEVEL3-260CG
- Qual Device LM519QPSQX/NO is qualified at LEVEL1-260CG
- Qual Device DP83848QSQNOPB is qualified at LEVEL3-260CG

| | | Test 0 | Group D – Die | e Fa | abrio | cation Reliability Tests | | | | | | | | | | | |
|---|-----------|--------|---------------|-------------|-------|---------------------------|-------------------------|-------------------------|---------------------------|-------------------------|-----------------------|-----------------------|-----------------------|--|-----------------------|-----------------------|-----------------------|
| П | EM | D1 | JESD61 | | | Electromigration | | Completed Per Process | Completed Per Process | Completed Per Process | | | | | | | |
| | EIVI | ן יט | JESDOI | - | - | Electromigration | - | Technology Requirements | Technology Requirements | Technology Requirements | | | | | | | |
| П | TDDB | D2 | JESD35 | | | Time Dependant Dielectric | | Completed Per Process | Completed Per Process | Completed Per Process | | | | | | | |
| | ТООВ | 02 | JESDSS | - | - | Breakdown | - | Technology Requirements | Technology Requirements | Technology Requirements | | | | | | | |
| П | HCI | D3 | JESD60 & | | | Hot Injection Carrier | | Completed Per Process | Completed Per Process | Completed Per Process | | | | | | | |
| | псі | 03 | 28 | - | - | not injection carrier | - | Technology Requirements | Technology Requirements | Technology Requirements | | | | | | | |
| | NBTI | D4 | | | | | | | Negative Bias Temperature | | Completed Per Process | Completed Per Process | Completed Per Process | | | | |
| | NBII D4 - | - | - | Instability | - | Technology Requirements | Technology Requirements | Technology Requirements | | | | | | | | | |
| П | SM | D5 | | | - | | | | | | | | Strong Migration | | Completed Per Process | Completed Per Process | Completed Per Process |
| | SM | Do | - | - | | Stress Migration | | Technology Requirements | Technology Requirements | Technology Requirements | | | | | | | |

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C
Grade 1 (or Q): -40°C to +125°C
Grade 2 (or T): -40°C to +105°C
Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20201209-137458



TI Information **Selective Disclosure**

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

0.8mil / 1.3mil PCC wire in QFN (Q100H, Q006, Grade 1, -40/125C & Grade 2, -40/105C) Approved 12-Jul-2022

Product Attributes

| Attributes | Qual Device: DP83848QSQNOPB | Qual Device: <u>LM26420Q1XQMGR</u> | Qual Device: <u>LM5119QPSQX/NO</u> |
|------------------------|--------------------------------|---------------------------------------|---------------------------------------|
| Operating Temp Range | -40 to +105 C | -40 to +125 C | -40 to +125 C |
| Automotive Grade Level | Grade 2 | Grade 1 | Grade 1 |
| Product Function | Interface | Interface | Interface |
| Wafer Fab Supplier | MAINEFAB | MAINEFAB | MAINEFAB |
| Die Revision | A | В | A |
| Assembly Site | TIEMA | TIEMA | TIEMA |
| Package Type | WQFN; 6 x 6 MM | QFN; 5 X 5 MM | QFN: 5 X 5 MM |
| Package Designator | RTA | RUM | RTV |
| Ball/Lead Count | 40 | 16 | 32 |

⁻ QBS: Qual By Similarity

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

| Тур | e # | Test Spec | Min Lot Qty | SS/Lot | Test Name / Condition | Duration | Qual Device: DP83848QSQNOPB | Qual Device: LM26420Q1XQMGR | Qual Device: LM5119QPSQX/NO |
|-----|------|-------------------------------------|----------------|----------|---|------------------|--------------------------------|--------------------------------|--------------------------------|
| | | Test Group A | – Accelerate | d Enviro | nment Stress Tests | | | | |
| PC | A1 | - | 3 | 22 | SAM Analysis, Pre Stress | Completed | 3/66/0 | 3/66/0 | 3/66/0 |
| PC | A1 | JEDEC J-STD-020 JESD22- A113 | 3 | 77 | Preconditioning | Level 3- 260C | No fails | No fails | No fails |
| PC | A1 | - | 3 | 22 | SAM Analysis, Post Precon | Completed | 3/66/0 | 3/66/0 | 3/66/0 |
| HAS | T A2 | JEDEC JESD22-A110 | 3 | 77 | Biased HAST, 110C/85%RH | 264 Hours | - | 3/231/0 | 3/231/0 |
| HAS | T A2 | - | 3 | 1 | Cross Section, Post bHAST 264 Hours | Completed | - | - | - |
| HAS | T A2 | - | 3 | 30 | Wire Bond Shear, Post bHast, 264 Hours | Wires | - | - | - |
| HAS | T A2 | - | 3 | 30 | Bond Pull over Stitch, post bHAST, 264 Hours | Wires | - | - | - |
| HAS | T A2 | - | 3 | 30 | Bond Pull over Ball, Post bHAST, 264 Hours | Wires | - | - | - |
| HAS | T A2 | JEDEC JESD22-A110 | 3 | 77 | Biased HAST, 110C/85%RH | 528 Hours | - | 3/210/0 | 3/210/0 |
| HAS | T A2 | - | 3 | 1 | Cross Section, Post bHAST 528 Hours | Completed | - | 3/3/0 | 3/3/0 |
| HAS | T A2 | - | 3 | 22 | SAM Analysis, Post bHAST, 528 Hours | Completed | - | 3/66/0 | 3/66/0 |
| HAS | T A2 | - | 3 | 30 | Wire Bond Shear, Post bHast, 528 Hours | Wires | - | 3/90/0 | 3/90/0 |
| HAS | T A2 | - | 3 | 30 | Bond Pull over Stitch, post bHAST, 528 Hours | Wires | - | 3/90/0 | 3/90/0 |
| HAS | T A2 | - | 3 | 30 | Bond Pull over Ball, Post bHAST, 528 Hours | Wires | - | 3/90/0 | 3/90/0 |
| TC | A4 | JEDEC JESD22-A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 500 Cycles | 3/231/0 | 3/231/0 | 3/231/0 |
| тс | A4 | - | 3 | 1 | Cross Section, Post T/C 500 Cycles | Completed | 3/3/0 | 3/3/0 | 3/3/0 |
| TC | A4 | - | 3 | 22 | SAM Analysis, Post T/C, 500 Cycles | Completed | 3/66/0 | 3/66/0 | 3/66/0 |
| TC | A4 | - | 3 | 30 | Wire Bond Shear, Post T/C 500 Cycles | Wires | - | - | - |
| тс | A4 | - | 3 | 30 | Bond Pull over Stitch Post T/C 500 Cycles | Wires | - | - | - |
| тс | A4 | - | 3 | 30 | Bond Pull over Ball Post T/C 500 Cycles | Wires | - | - | - |

| Туре | # | Test Spec | Min Lot Qty | SS/Lot | Test Name / Condition | Duration | Qual Device: DP83848QSQNOPB | Qual Device: LM26420Q1XQMGR | Qual Device: LM5119QPSQX/NO |
|------|----|-------------------------------------|----------------|--------|---|-------------|--------------------------------|--------------------------------|--------------------------------|
| TC | A4 | JEDEC JESD22-A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 1000 Cycles | 3/210/0 | 3/210/0 | 3/210/0 |
| TC | A4 | - | 3 | 1 | Cross Section, Post T/C 1000 Cycles | Completed | 3/3/0 | 3/3/0 | 3/3/0 |
| TC | A4 | - | 3 | 22 | SAM Analysis, Post T/C, 1000 Cycles | Completed | 3/66/0 | 3/66/0 | 3/66/0 |
| TC | A4 | - | 3 | 30 | Wire Bond Shear, Post T/C 1000 Cycles | Wires | 3/90/0 | 3/90/0 | 3/90/0 |
| TC | A4 | - | 3 | 30 | Bond Pull over Stitch, Post T/C, 1000 Cycles | Wires | 3/90/0 | 3/90/0 | 3/90/0 |
| TC | A4 | - | 3 | 30 | Bond Pull over Ball, Post T/C, 1000 Cycles | Wires | 3/90/0 | 3/90/0 | 3/90/0 |
| PTC | A5 | JEDEC JESD22-A105 | 1 | 45 | Power Temperature Cycle -40/125C | 1000 Cycles | - | - | - |
| PTC | A5 | JEDEC JESD22-A105 | 1 | 45 | Power Temperature Cycle -40/125C | 2000 Cycles | - | - | - |
| HTSL | A6 | JEDEC JESD22-A103 | 3 | 45 | High Temp Storage Bake 150C | 1000 Hours | - | - | 3/135/0 |
| HTSL | A6 | - | 3 | 1 | Cross Section, Post HTSL 1000 Hours | Completed | - | - | - |
| HTSL | A6 | JEDEC JESD22-A103 | 3 | 44 | High Temp Storage Bake 150C | 2000 Hours | - | - | 3/132/0 |
| HTSL | A6 | - | 3 | 1 | Cross Section, Post HTSL 2000 Hours | Completed | - | - | 3/3/0 |
| | | Test Group | | | | | | | |
| WBS | C1 | AEC Q100-001 | 3 | 30 | Wire Bond Shear, Cpk>1.67 | Wires | 3/90/0 | 3/90/0 | 3/90/0 |
| WBP | C2 | MIL-STD883 Method 2011 | 3 | 30 | Bond Pull over Ball, Cpk >1.67 | Wires | 3/90/0 | 3/90/0 | 3/90/0 |

A1 (PC): Preconditioning

Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20201209-137458

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